

Rectifier Diode

Type W1608NC400 to W1608NC500

Old Type No.: SW36-45CXC680

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	4000-5000	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	4100-5100	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, $T_{sink}=55^{\circ}C$, (note 2)	1608	A
$I_{F(AV)M}$	Maximum average forward current, $T_{sink}=100^{\circ}C$, (note 2)	1140	A
$I_{F(AV)M}$	Maximum average forward current, $T_{sink}=100^{\circ}C$, (note 3)	735	A
$I_{F(RMS)M}$	Nominal RMS forward current, $T_{sink}=25^{\circ}C$, (note 2)	2930	A
$I_{F(d.c.)}$	D.C. forward current, $T_{sink}=25^{\circ}C$, (note 4)	2660	A
I_{FSM}	Peak non-repetitive surge $t_p=10ms$, $V_{rm}=0.6V_{RRM}$, (note 5)	13.0	kA
I_{FSM2}	Peak non-repetitive surge $t_p=10ms$, $V_{rm}\leq 10V$, (note 5)	14.3	kA
I^2t	I^2t capacity for fusing $t_p=10ms$, $V_{rm}=0.6V_{RRM}$, (note 5)	0.85	kA^2s
I^2t	I^2t capacity for fusing $t_p=10ms$, $V_{rm}\leq 10V$, (note 5)	1.02	kA^2s
$T_{j op}$	Operating temperature range	-55 to +160	$^{\circ}C$
T_{stg}	Storage temperature range	-55 to +200	$^{\circ}C$

Notes:-

- 1) De-rating factor of 0.13% per $^{\circ}C$ is applicable for T_j below $25^{\circ}C$.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Single side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, $160^{\circ}C$ T_j initial.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V _{FM}	Maximum peak forward voltage	-	-	2.48	I _{TM} =3000A	V
V _{FM}	Maximum peak forward voltage	-	-	3.42	I _{TM} =4820A	V
V _{T0}	Threshold voltage	-	-	0.975		V
r _T	Slope resistance	-	-	0.501		mΩ
I _{RRM}	Peak reverse current	-	-	50	Rated V _{RRM}	mA
I _{RRM}	Peak reverse current	-	-	50	Rated V _{RRM} , T _j =25°C	mA
R _{thJK}	Thermal resistance, junction to heatsink	-	-	0.022	Double side cooled	K/W
		-	-	0.044	Single side cooled	K/W
F	Mounting force	19	-	26		kN
W _t	Weight	-	480	-		g

Notes:-

1) Unless otherwise indicated T_j=160°C.

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V_{RRM} V	V_{RSM} V	V_R DC V
40	4000	4100	2000
42	4200	4300	2040
44	4400	4500	2080
46	4600	4700	2120
48	4800	4900	2160
50	5000	5100	2200

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_0 + \sqrt{V_0^2 + 4 \cdot ff^2 \cdot r_s \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_s} \quad \text{and:} \quad W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j \max} - T_{Hs}$$

Where $V_0=0.975V$, $r_s=0.501m\Omega$,

R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance							
Conduction Angle	30°	60°	90°	120°	180°	270°	d.c.
Square wave Double Side Cooled	0.0312	0.0285	0.0267	0.0255	0.0240	0.0228	0.0220
Square wave Single Side Cooled	0.0543	0.0513	0.0496	0.0484	0.0469	0.0455	0.0440
Sine wave Double Side Cooled	0.0268	0.0257	0.0241	0.0233	0.022		
Sine wave Single Side Cooled	0.0509	0.0482	0.0471	0.0463	0.044		

Form Factors							
Conduction Angle	30°	60°	90°	120°	180°	270°	d.c.
Square wave	3.464	2.449	2	1.732	1.414	1.149	1
Sine wave	3.98	2.778	2.22	1.879	1.57		

5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F , on page 5 is represented in two ways;

- (i) the well established V_0 and r_s tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	160°C Coefficients
A	1.663616	1.070367
B	-0.1331571	-0.05305324
C	2.296403×10^{-4}	4.425432×10^{-4}
D	0.01520457	9.572917×10^{-3}

5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}} \right)$$

Where $p = 1$ to n , n is the number of terms in the series and:

t = Duration of heating pulse in seconds.

r_t = Thermal resistance at time t .

r_p = Amplitude of p_{th} term.

τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

D.C. Single Side Cooled					
Term	1	2	3	4	5
r_p	0.0291698	4.295845×10^{-3}	7.57109×10^{-3}	2.195801×10^{-3}	1.628753×10^{-3}
τ_p	5.67822	1.123602	0.1407857	0.014381914	1.272749×10^{-3}

D.C. Double Side Cooled				
Term	1	2	3	4
r_p	0.01177146	6.485814×10^{-3}	2.471007×10^{-3}	1.607109×10^{-3}
τ_p	0.9495346	0.1337950	0.01636628	1.255571×10^{-3}

Curves

Figure 1 - Forward characteristics of Limit device

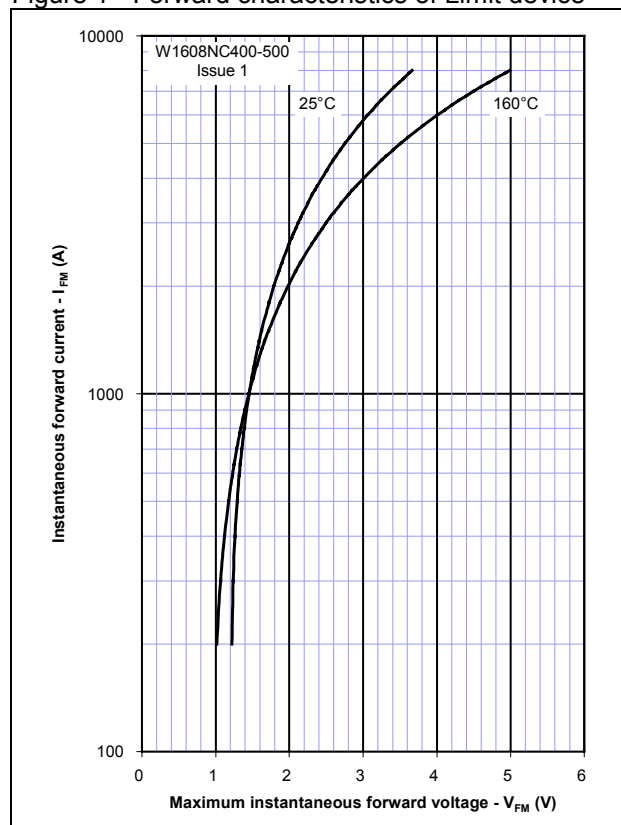


Figure 2 - Transient thermal impedance

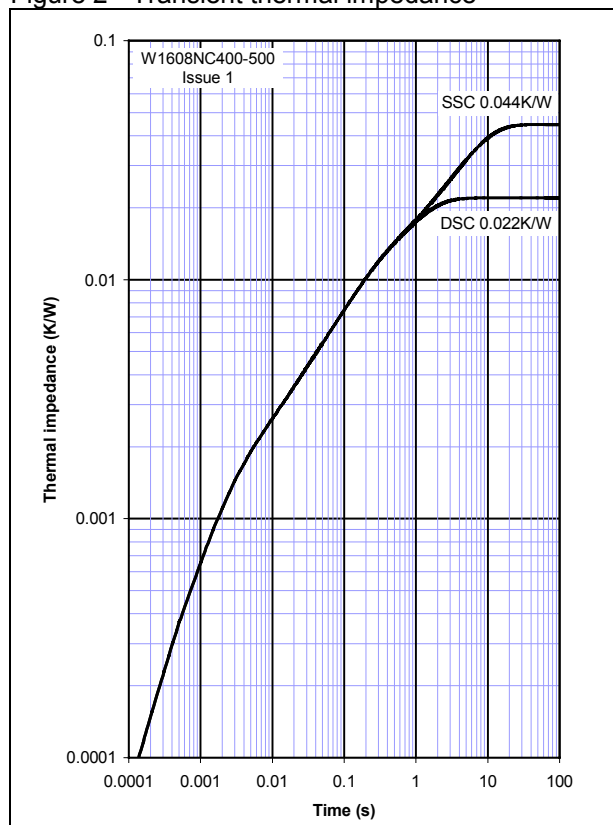


Figure 3 - Maximum surge Rating

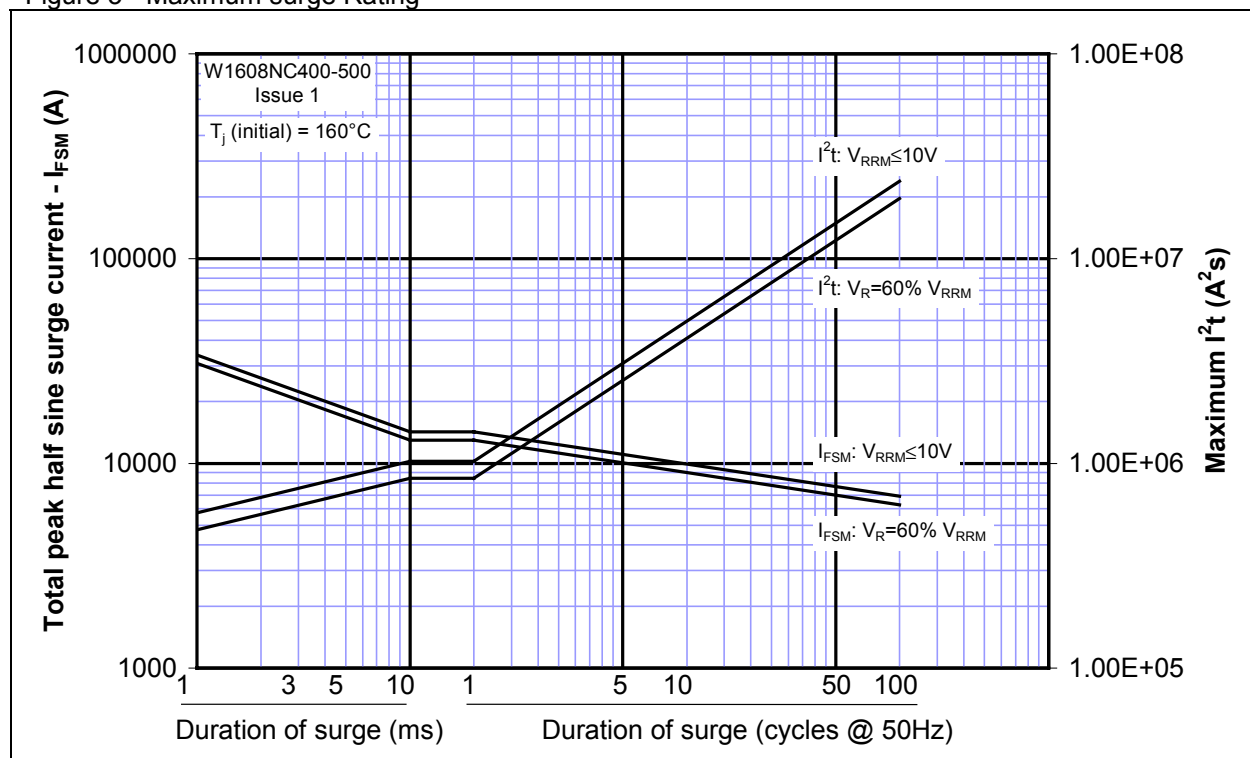


Figure 4 – Forward current vs. Power dissipation – Double Side Cooled

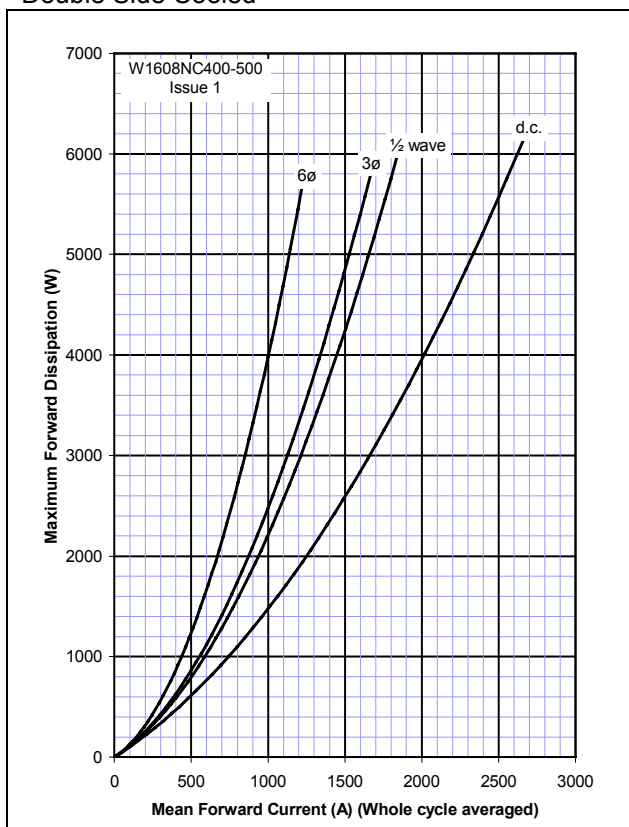


Figure 5 – Forward current vs. Heatsink temperature - Double Side Cooled

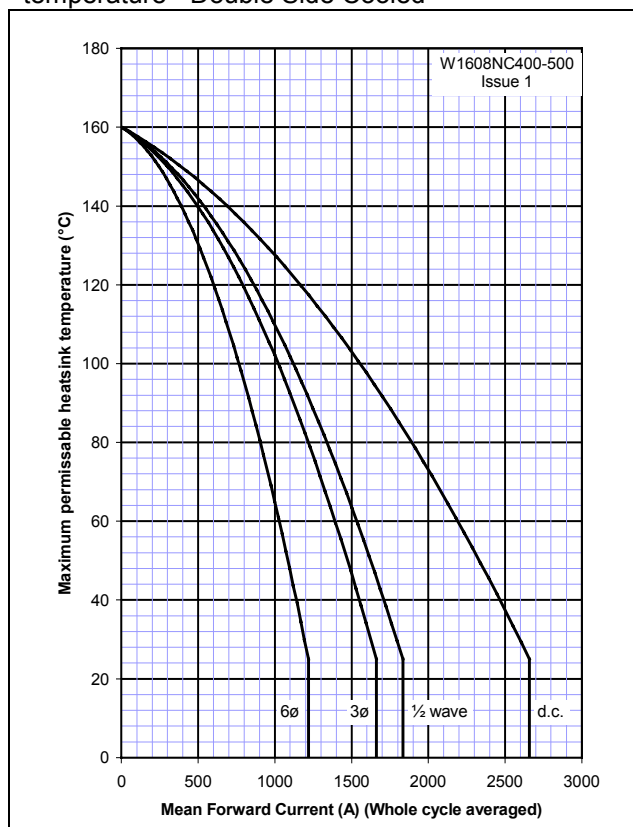


Figure 6 – Forward current vs. Power dissipation – Single Side Cooled

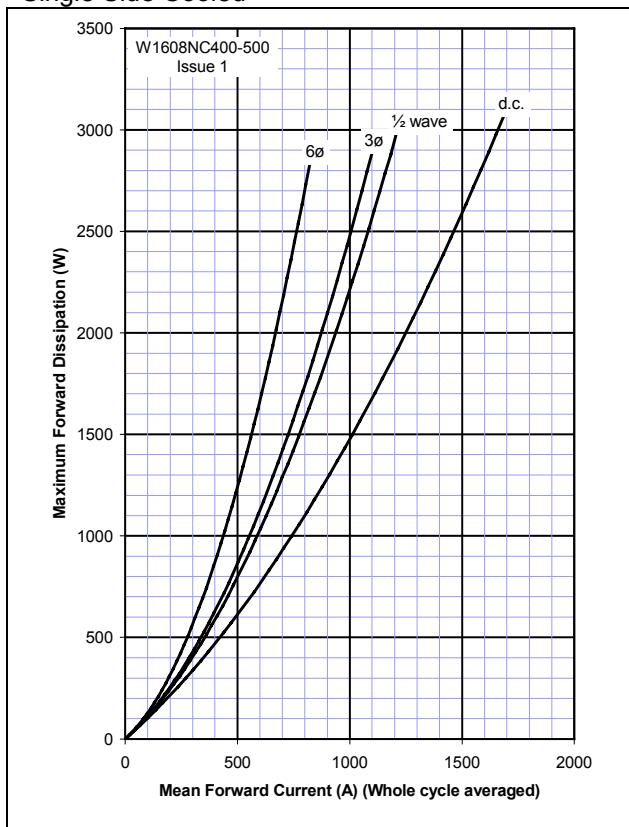
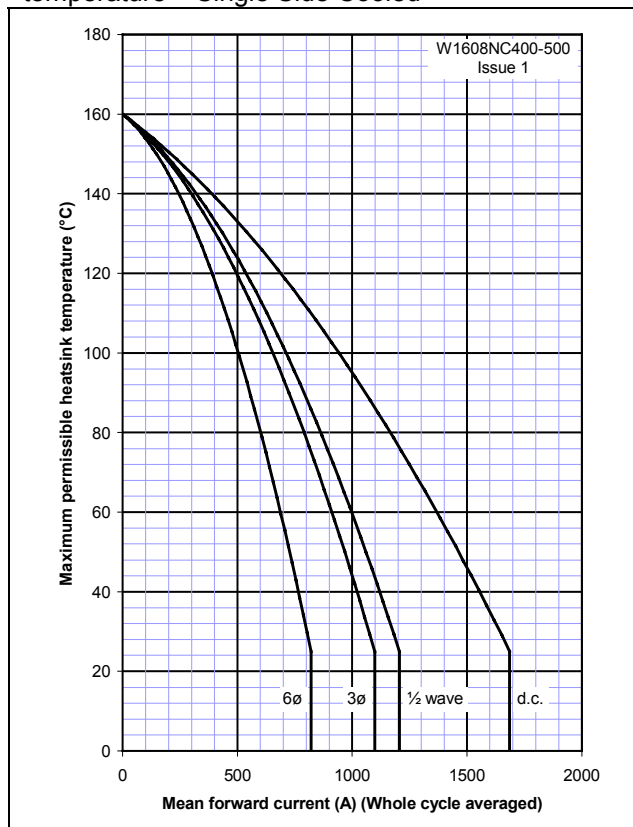
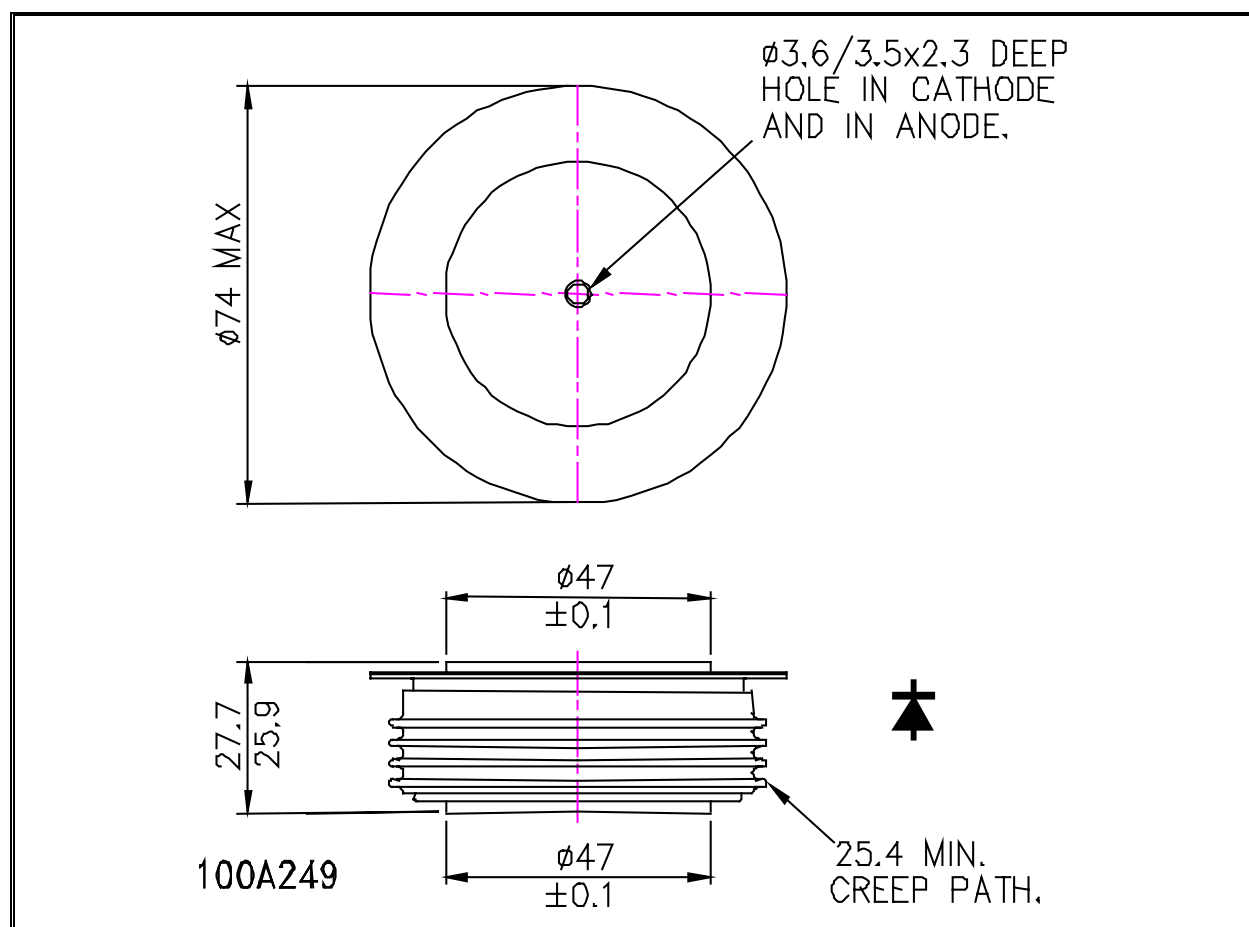


Figure 7 – Forward current vs. Heatsink temperature – Single Side Cooled



Outline Drawing & Ordering Information



ORDERING INFORMATION			
(Please quote 10 digit code as below)			
W1608	NC	♦♦	0
Fixed Type Code	Fixed outline code	Voltage code $V_{DRM}/100$ 40-50	Fixed turn-off time code

Order code: W1608NC420 – 4200V V_{RRM} , 33.1mm clamp height capsule.

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